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Vishay Siliconix

Automotive P-Channel 60 V (D-S) 175 °C MOSFET



Marking code: 9NYXX

PRODUCT SUMMARY					
V _{DS} (V)	-60				
$R_{DS(on)}$ max. (Ω) at V_{GS} = -10 V	0.335				
$R_{DS(on)}$ max. (Ω) at $V_{GS} = -4.5 \text{ V}$	0.500				
I _D (A)	-1.7				
Configuration	Single				

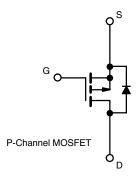
FEATURES

- TrenchFET® power MOSFET
- AEC-Q101 qualified
- 100 % R_q and UIS tested
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912





ROHS COMPLIANT HALOGEN FREE



ORDERING INFORMATION	
Package	SOT-23
Lead (Pb)-free and halogen-free	SQ2309CES (for detailed order number please see www.vishay.com/doc?79771)

ABSOLUTE MAXIMUM RATINGS (T _C = 25 °C, unless otherwise noted)					
PARAMETER	SYMBOL	LIMIT	UNIT		
Drain-source voltage		V _{DS}	-60	V	
Gate-source voltage		V_{GS}	± 20		
Continuous drain current	T _C = 25 °C	_	-1.7		
	T _C = 125 °C	ID	-1		
Continuous source current (diode conduction)	I _S	-2.6	Α		
Pulsed drain current ^a	I _{DM}	-6.8			
Single pulse avalanche current	L = 0.1 mH	I _{AS}	-6.8		
Single pulse avalanche energy	L = 0.111111	E _{AS}	2.3	mJ	
Maximum power dissipation	T _C = 25 °C	D	2	W	
	T _C = 125 °C	- P _D	0.6		
Operating junction and storage temperature ra	T _J , T _{stg}	-55 to +175	°C		

THERMAL RESISTANCE RATINGS					
PARAMETER		SYMBOL	LIMIT	UNIT	
Junction-to-ambient	PCB mount b	R_{thJA}	166	°C/W	
Junction-to-foot (drain)		R_{thJF}	73	C/ VV	

Notes

- a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %
- b. When mounted on 1" square PCB (FR4 material)



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Document Number: 62211

PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
Static							
Drain-source breakdown voltage	V_{DS}	$V_{GS} = 0 \text{ V}, I_D = -250 \mu\text{A}$		-60	-	-	V
Gate-source threshold voltage	V _{GS(th)}	V _{DS} =	V _{GS} , I _D = -250 μA	-1.5	-2.0	-2.5	V
Gate-source leakage	I _{GSS}	V _{DS} =	0 V, V _{GS} = ± 20 V	-	-	± 100	nA
		$V_{GS} = 0 V$	V _{DS} = -60 V	-	-	-1	μΑ
Zero gate voltage drain current	I _{DSS}	V _{GS} = 0 V	V _{DS} = -60 V, T _J = 125 °C	-	-	-50	
		V _{GS} = 0 V	V _{DS} = -60 V, T _J = 175 °C	-	-	-150	
On-state drain current ^a	I _{D(on)}	V _{GS} = -10 V	$V_{DS} \le -5 \text{ V}$	-5	-	-	Α
		V _{GS} = -10 V	I _D = -1.25 A	-	0.268	0.370	
Duning and the seriet and 3	0	V _{GS} = -10 V	I _D = -1.25 A, T _J = 125 °C	-	-	0.567	0
Drain-source on-state resistance a	R _{DS(on)}	V _{GS} = -10 V	I _D = -1.25 A, T _J = 175 °C	-	-	0.704	Ω
		V _{GS} = -4.5 V	I _D = -1 A	-	0.354	0.500	
Forward transconductance b	9 _{fs}	V_{DS}	= -5 V, I _D = -1 A	1	1.8	-	S
Dynamic ^b							
Input capacitance	C _{iss}		V _{DS} = -25 V, f = 1 MHz	-	211	265	pF
Output capacitance	Coss	$V_{GS} = 0 V$		1	30	40	
Reverse transfer capacitance	C _{rss}			1	21	30	
Total gate charge c	Q_g			-	5.5	8.5	nC
Gate-source charge ^c	Q _{gs}	V _{GS} = -10 V	$V_{DS} = -30 \text{ V}, I_{D} = -1 \text{ A}$	1	0.8	-	
Gate-drain charge ^c	Q _{qd}			1	1.3	-	
Gate resistance	R_g		f = 1 MHz		5.40	14.80	Ω
Turn-on delay time ^c	t _{d(on)}				5	8	
Rise time ^c	t _r	$V_{DD} = -30 \text{ V}, \text{ R}_L = 30 \Omega$ $I_D \cong -3 \text{ A}, \text{ V}_{GEN} = -10 \text{ V}, \text{ R}_g = 1 \Omega$		1	9	14	ns
Turn-off delay time ^c	t _{d(off)}			-	12	18	
Fall time ^c	t _f			-	9	14	
Source-Drain Diode Ratings and Charac	teristics b	•					
Pulsed current a	I _{SM}			-	-	-6.8	Α
Forward voltage	V _{SD}	I _F = -1.5 A, V _{GS} = 0 V		-	-0.85	-1.2	V
Body diode reverse recovery time	t _{rr}	l _F = -1.2 A, di/dt = 100 A/μs		-	23	46	ns
Body diode reverse recovery charge	Qrr			-	24	48	nC
Reverse recovery fall time	ta			-	20	-	
Reverse recovery rise time	t _b			-	3	-	ns
Body diode peak reverse recovery current	I _{RM(REC)}			-	-3.1	-	Α

Notes

- a. Pulse test; pulse width $\leq 300~\mu s,~duty~cycle \leq 2~\%$
- b. Guaranteed by design, not subject to production testing
- c. Independent of operating temperature

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



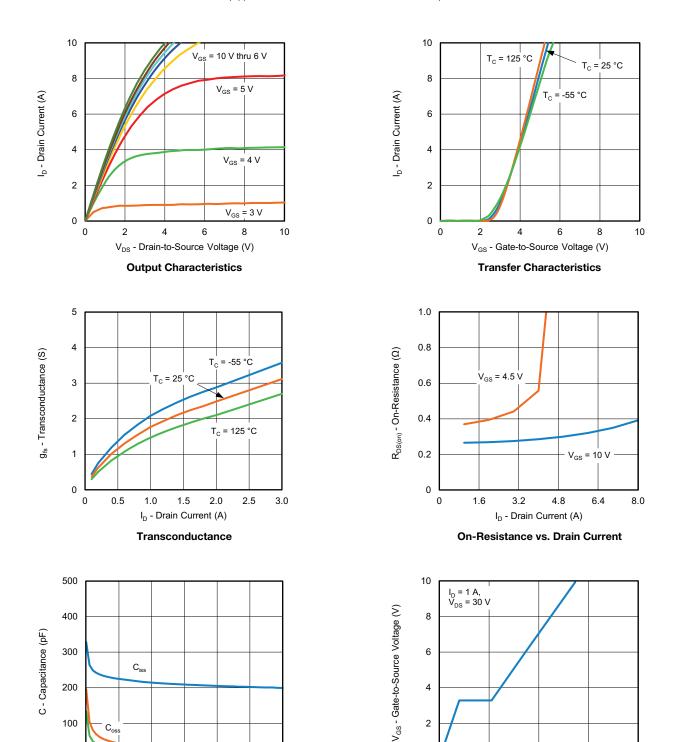
0

10

V_{DS} - Drain-to-Source Voltage (V)

Capacitance

TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



60

0

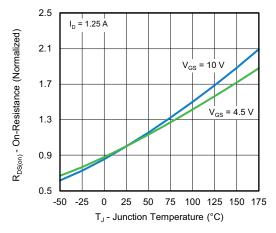
0

Q_q - Total Gate Charge (nC)

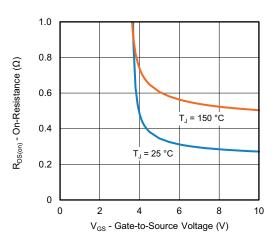
Gate Charge



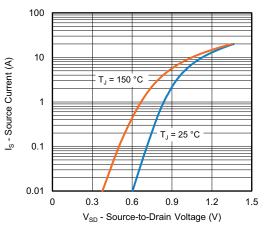
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



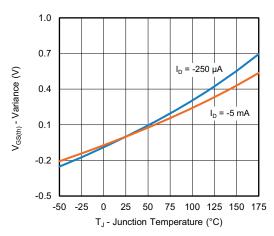
On-Resistance vs. Junction Temperature



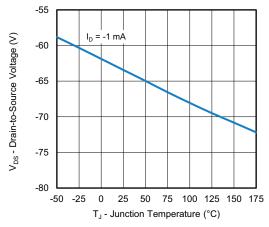
On-Resistance vs. Gate-to-Source Voltage



Source Drain Diode Forward Voltage



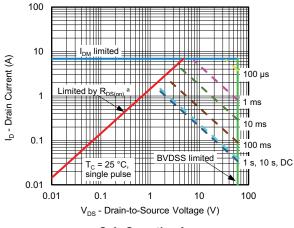
Threshold Voltage



Drain Source Breakdown vs. Junction Temperature



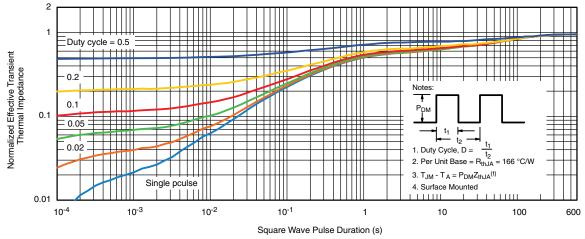
THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Safe Operating Area

Note

a. V_{GS} > minimum V_{GS} at which $R_{DS(on)}$ is specified

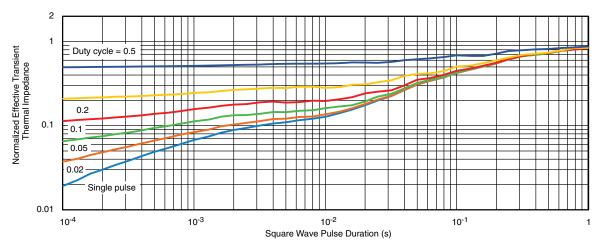


Normalized Thermal Transient Impedance, Junction-to-Ambient

ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000



THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Foot

Notes

- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
 - Normalized Transient Thermal Impedance Junction-to-Foot (25 °C) are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package / tape drawings, part marking, and reliability data, see www.vishay.com/ppg262211.

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SOT-23 (TO-236): 3-LEAD







Dim	MILLI	METERS	INCHES		
	Min	Max	Min	Max	
Α	0.89	1.12	0.035	0.044	
A ₁	0.01	0.10	0.0004	0.004	
A ₂	0.88	1.02	0.0346	0.040	
b	0.35	0.50	0.014	0.020	
С	0.085	0.18	0.003	0.007	
D	2.80	3.04	0.110	0.120	
E	2.10	2.64	0.083	0.104	
E ₁	1.20	1.40	0.047	0.055	
е	0.95 BSC		0.0374 Ref		
e ₁	1.90 BSC		0.0748 Ref		
L	0.40	0.60	0.016	0.024	
L ₁	0.64 Ref		0.025 Ref		
S	0.50 Ref		0.020 Ref		
q	3°	8°	3°	8°	
FCN: S-03946-Rev K 09-	lul-01	•			

ECN: S-03946-Rev. K, 09-Jul-01

DWG: 5479

Document Number: 71196 www.vishay.com 09-Jul-01



RECOMMENDED MINIMUM PADS FOR SOT-23



Recommended Minimum Pads Dimensions in Inches/(mm)

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APPLICATION NOTE



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